

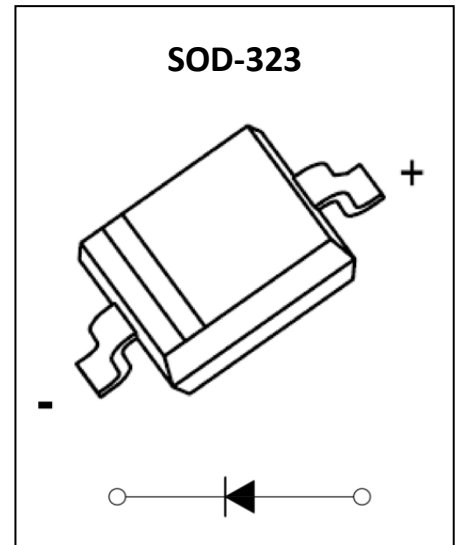


BAT54WS Schottky Barrier Diode

Feature

- Extremely Fast Switch Speed
- Low Forward Voltage

MARKING:



ABSOLUTE MAXIMUM RATINGS ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

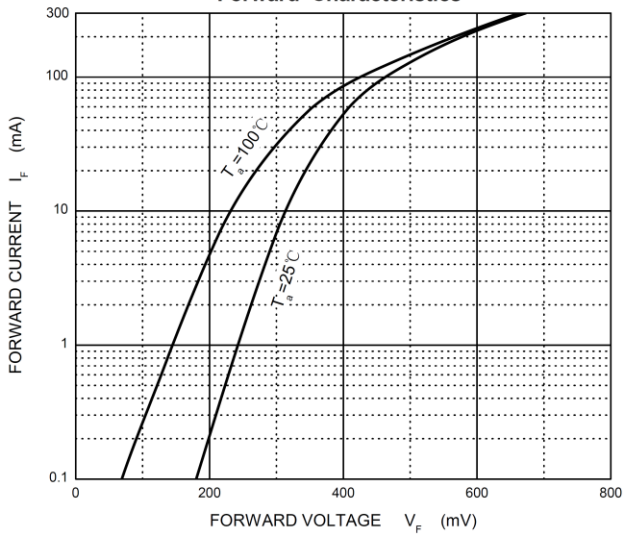
Parameter	Symbol	Value	Unit
DC reverse voltage	V_R	30	V
Mean rectifying current	I_O	0.1	A
Non-repetitive Peak Forward Surge Current @ $t=8.3\text{ms}$	I_{FSM}	0.6	A
Power Dissipation	P_D	0.15	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	667	$^{\circ}\text{C}/\text{W}$
Junction Temperature	T_J	125	$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	-55 ~ +150	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

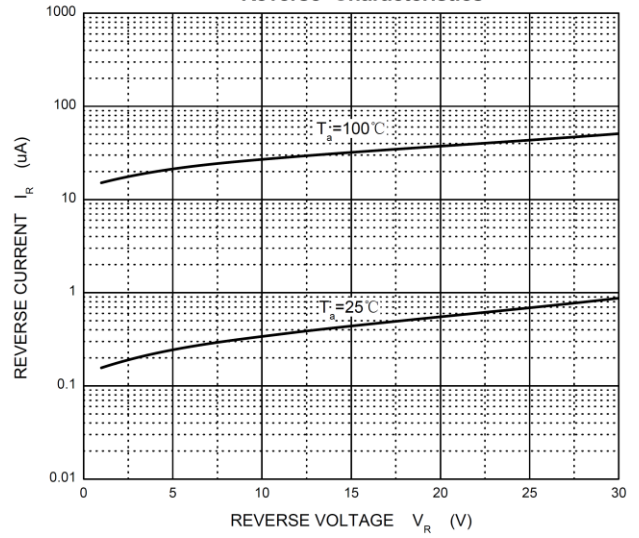
Parameter	Symbol	Test Condition	Min	Type	Max	Unit
Reverse breakdown voltage	$V_{(BR)}$	$I_R=100\mu\text{A}$	30			V
Forward voltage	V_{F1}	$I_F=0.1\text{mA}$			0.24	V
	V_{F2}	$I_F=1\text{mA}$			0.32	V
	V_{F3}	$I_F=10\text{mA}$			0.40	V
	V_{F4}	$I_F=30\text{mA}$			0.50	V
	V_{F5}	$I_F=100\text{mA}$			1	V
Reverse current	I_R	$V_R=25\text{V}$			2	μA
Reverse recovery time	t_{rr}	$I_F=10\text{mA}$, $I_R=10\text{mA}$ to 1mA , $R_L=100\Omega$			5	ns
Capacitance between terminals	C_T	$V_R=1\text{V}$, $f=1\text{MHz}$			10	pF

Typical Characteristics

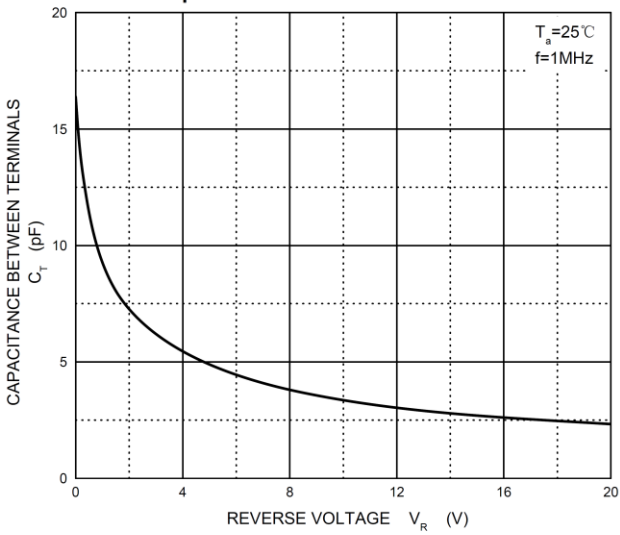
Forward Characteristics



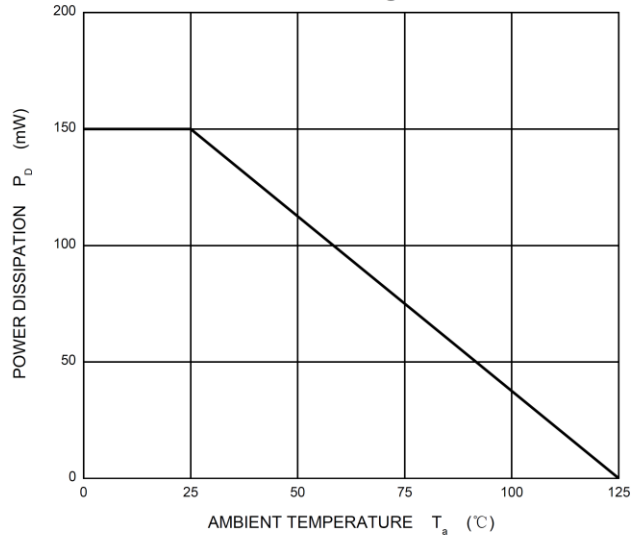
Reverse Characteristics



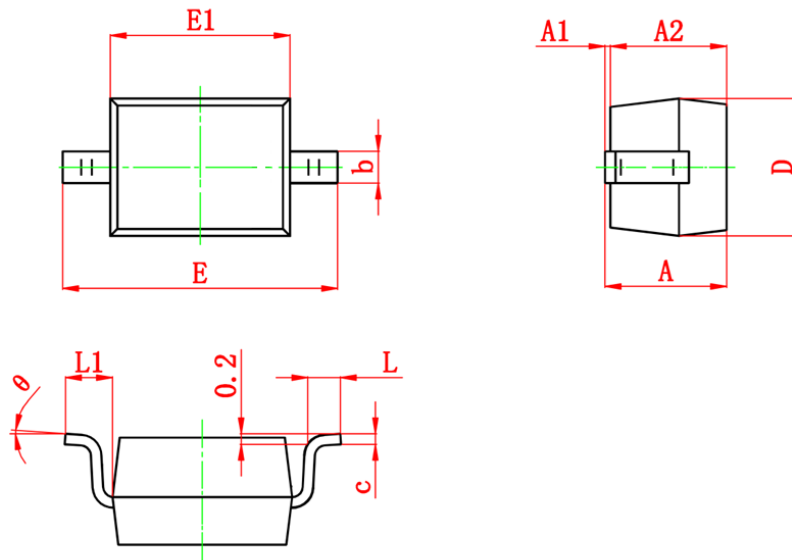
Capacitance Characteristics Per Diode



Power Derating Curve



SOD-323 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.150MAX		0.045MAX	
A1	0.000	0.100	0.000	0.004
A2	0.800	0.900	0.031	0.035
b	0.250	0.400	0.010	0.016
c	0.080	0.180	0.003	0.007
D	1.200	1.400	0.047	0.055
E	2.500	2.800	0.098	0.110
E1	1.600	1.800	0.063	0.071
L	0.200	0.450	0.008	0.018
L1	0.475REF		0.019REF	
θ	0°	8°	0°	8°